



U74HC4066

CMOS IC

QUAD BILATERAL SWITCHES

DESCRIPTION

The UTC **U74HC4066** consists of four independent analog switches. Each switch has an Enable input (nE) which is active HIGH to decide the switch status.

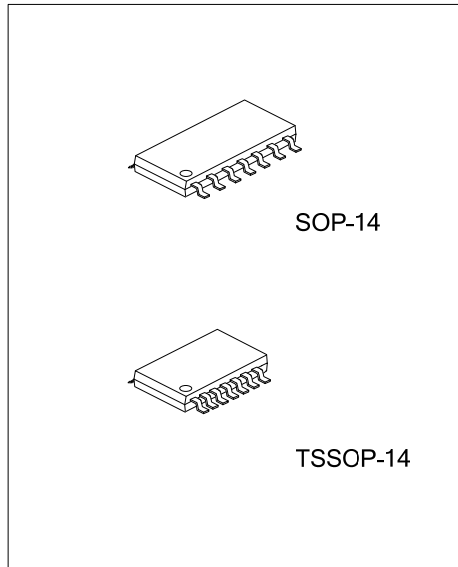
FEATURES

* Operation voltage range: 2~10V

* Very low "ON" resistance: $V_{CC}=4.5V, 50\Omega$

$V_{CC}=6V, 45\Omega$

$V_{CC}=9V, 35\Omega$

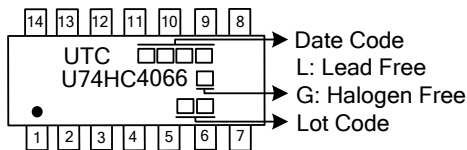


ORDERING INFORMATION

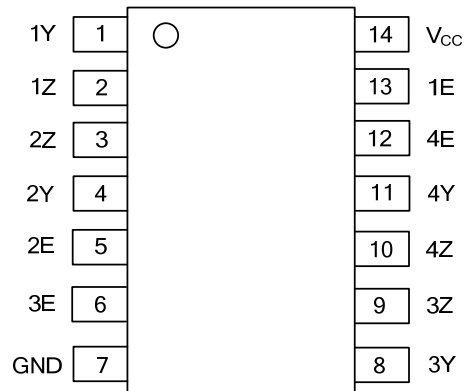
Ordering Number		Package	Packing
Lead Free	Halogen Free		
U74HC4066L-S14-R	U74HC4066G-S14-R	SOP-14	Tape Reel
U74HC4066L-P14-R	U74HC4066G-P14-R	TSSOP-14	Tape Reel

U74HC4066G-S14-R	(1) Packing Type	(1) R: Tape Reel
	(2) Package Type	(2) S14: SOP-14, P14: TSSOP-14
	(3) Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

MARKING



■ PIN CONFIGURATION

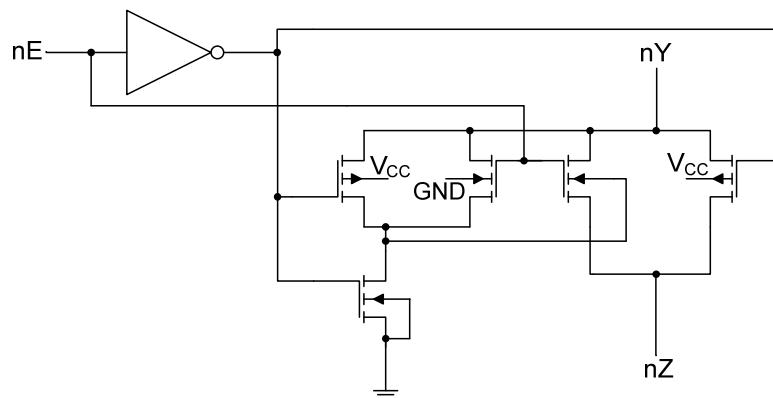


■ FUNCTION TABLE

INPUTS(nE)	SWITCH
H	ON
L	OFF

Note: H: High voltage level; L: Low voltage level.

■ LOGIC DIAGRAM



■ ABSOLUTE MAXIMUM RATING ($T_A=25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT	
Supply Voltage	V_{CC}	-0.5 ~ +11	V	
Input Diode Current	I_{IK}	± 20	mA	
Switch Diode Current	I_{SK}	± 20	mA	
Switch Current	I_S	± 25	mA	
V_{CC} or GND Current	I_{CC}	± 50	mA	
Power Dissipation	P_D	500	mW	
Derate above 70°C		SOP-14	8	mW/K
Derate above 60°C		TSSOP-14	5.5	mW/K
Storage Temperature	T_{STG}	-65 ~ +150	$^{\circ}\text{C}$	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V_{CC}		2.0	5.0	10.0	V
Input Voltage	V_{IN}		GND		V_{CC}	V
Switch Voltage	V_S		GND		V_{CC}	V
Input Transition Rise or Fall Rate	t_R, t_F	$V_{CC}=2.0\text{V}$		6	1000	ns
		$V_{CC}=4.5\text{V}$			500	ns
		$V_{CC}=6.0\text{V}$			400	ns
		$V_{CC}=10.0\text{V}$			250	ns
Operating Temperature	T_A		-40		85	$^{\circ}\text{C}$

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
High-Level Input Voltage		V _{IH}	V _{CC} =2.0V	1.5			V		
			V _{CC} =4.5V	3.15			V		
			V _{CC} =6.0V	4.2			V		
			V _{CC} =9.0V	6.3			V		
Low-Level Input Voltage		V _{IL}	V _{CC} =2.0V			0.50	V		
			V _{CC} =4.5V			1.35	V		
			V _{CC} =6.0V			1.80	V		
			V _{CC} =9.0V			2.70	V		
Input Leakage Current		I _{I(LEAK)}	V _{CC} =6V, V _{IN} =V _{CC} or GND			±1.0	μA		
			V _{CC} =10V, V _{IN} =V _{CC} or GND			±2.0	μA		
current per channel	OFF-state	I _S	V _{CC} =10V, V _{IN} =V _{IH} or V _{IL} , V _S =V _{CC} -GND			±1.0	μA		
	ON-state					±1.0	μA		
Quiescent Supply Current		I _Q	V _{CC} =6V, V _{IN} =V _{IS} =V _{OS} =V _{CC} or GND			20	μA		
			V _{CC} =10V, V _{IN} =V _{IS} =V _{OS} =V _{CC} or GND			40	μA		
ON-resistance		Peak	V _{CC} =4.5V, I _S =1mA, V _{IN} =V _{IH} or V _{IL} , V _{IS} =V _{CC} to GND		54	118	Ω		
			V _{CC} =6.0V, I _S =1mA, V _{IN} =V _{IH} or V _{IL} , V _{IS} =V _{CC} to GND		42	105	Ω		
			V _{CC} =9.0V, I _S =1mA, V _{IN} =V _{IH} or V _{IL} , V _{IS} =V _{CC} to GND		32	88	Ω		
			V _{CC} =2.0V, I _S =100μA, V _{IN} =V _{IH} or V _{IL} , V _{IS} =GND		80		Ω		
			Rail	V _{CC} =4.5V, I _S =1mA, V _{IN} =V _{IH} or V _{IL} , V _{IS} =GND		35	95	Ω	
				V _{CC} =6.0V, I _S =1mA, V _{IN} =V _{IH} or V _{IL} , V _{IS} =GND		27	82	Ω	
		V _{CC} =9.0V, I _S =1mA, V _{IN} =V _{IH} or V _{IL} , V _{IS} =GND			20	70	Ω		
		V _{CC} =2.0V, I _S =100μA, V _{IN} =V _{IH} or V _{IL} , V _{IS} =V _{CC}			100		Ω		
		V _{CC} =4.5V, I _S =1mA, V _{IN} =V _{IH} or V _{IL} , V _{IS} =V _{CC}			42	106	Ω		
		V _{CC} =6.0V, I _S =1mA, V _{IN} =V _{IH} or V _{IL} , V _{IS} =V _{CC}			35	94	Ω		
		V _{CC} =9.0V, I _S =1mA, V _{IN} =V _{IH} or V _{IL} , V _{IS} =V _{CC}			27	78	Ω		
		Maximum variation of ON-resistance between any two channels		ΔR _{ON}	V _{CC} =4.5V, V _{IN} =V _{IH} or V _{IL} , V _{IS} =V _{CC} to GND		5		Ω
					V _{CC} =6.0V, V _{IN} =V _{IH} or V _{IL} , V _{IS} =V _{CC} to GND		4		Ω
					V _{CC} =9.0V, V _{IN} =V _{IH} or V _{IL} , V _{IS} =V _{CC} to GND		3		Ω

■ DYNAMIC CHARACTERISTICS (T_A=25°C, GND=0V; t_R=t_F=6ns; C_L=50pF)

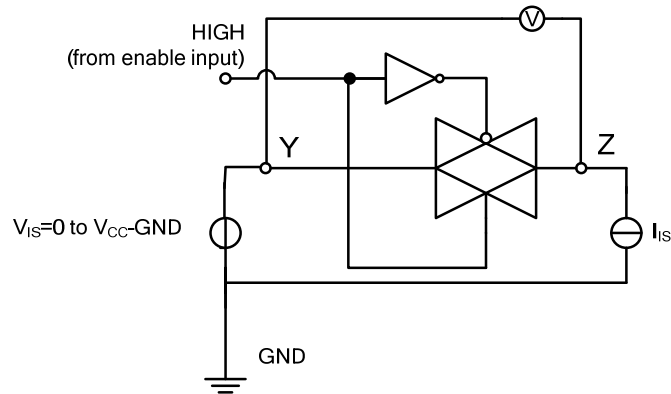
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Propagation Delay From V _{IS} to V _{OS}	t _{PHL} /t _{PLH}	V _{CC} =2.0V, R _L =∞		8	75	ns
		V _{CC} =4.5V, R _L =∞		3	15	ns
		V _{CC} =6.0V, R _L =∞		2	13	ns
		V _{CC} =9.0V, R _L =∞		2	10	ns
Turn-ON Time from nE to V _{OS}	t _{PZH} /t _{PZL}	V _{CC} =2.0V, R _L =1KΩ		36	125	ns
		V _{CC} =4.5V, R _L =1KΩ		13	25	ns
		V _{CC} =6.0V, R _L =1KΩ		10	21	ns
		V _{CC} =9.0V, R _L =1KΩ		8	16	ns
Turn-OFF Time from nE to V _{OS}	t _{PHZ} /t _{PLZ}	V _{CC} =2.0V, R _L =1KΩ		44	190	ns
		V _{CC} =4.5V, R _L =1KΩ		16	38	ns
		V _{CC} =6.0V, R _L =1KΩ		13	33	ns
		V _{CC} =9.0V, R _L =1KΩ		16	26	ns
Sine-Wave Distortion	THD	V _{CC} =4.5V, V _{IS(P-P)} =4V, f=1kHz, R _L =10k		0.04		%
		V _{CC} =9V, V _{IS(P-P)} =8V, f=1kHz, R _L =10k		0.02		%
		V _{CC} =4.5V, V _{IS(P-P)} =4V, f=10kHz, R _L =10k		0.12		%
		V _{CC} =9V, V _{IS(P-P)} =8V, f=10kHz, R _L =10k		0.06		%
Switch OFF Signal Feed-Through (Note 1)	α _{OFF}	V _{CC} =4.5V, R _L =600Ω, f=1MHz		-50		dB
		V _{CC} =9V, R _L =600Ω, f=1MHz		-50		dB
Crosstalk Between any two Switches (Note 1)	α _{CT(S)}	V _{CC} =4.5V, R _L =600Ω, f=1MHz		-60		dB
		V _{CC} =9V, R _L =600Ω, f=1MHz		-60		dB
Crosstalk Voltage Between any input to any Switch (Peak-to-Peak Value)	V _(P-P)	V _{CC} =4.5V, R _L =600Ω, f=1MHz		110		mV
		V _{CC} =9V, R _L =600Ω, f=1MHz		220		mV
Minimum Frequency Response(-3dB) (Note 2)	f _{MAX}	V _{CC} =4.5V, R _L =50Ω, C _L =10pF		180		MHz
		V _{CC} =9V, R _L =50Ω, C _L =10pF		200		MHz
maximum switch capacitance	C _S			8		pF

Note 1. Adjust input voltage V_{IS} is 0dbm level (0dbm=1mW into 600Ω)

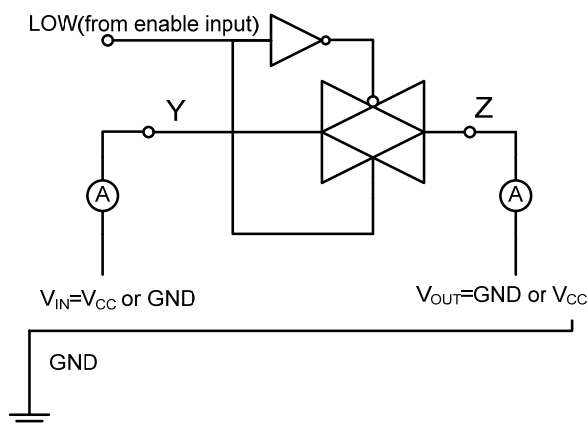
2. Adjust input voltage V_{IS} is 0dbm level at V_{OS} for 1MHz (0dbm=1mW into 50Ω)

■ TEST CIRCUIT AND WAVEFORMS

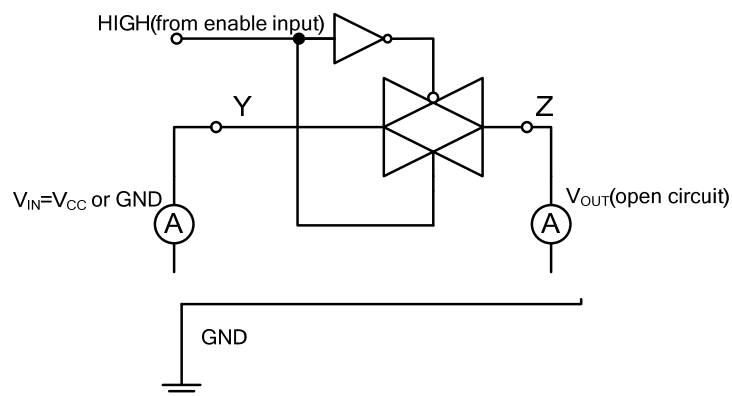
Test circuit for measuring ON-resistance (Ron)



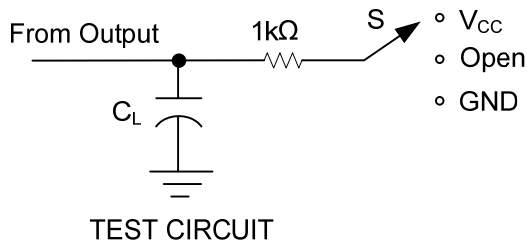
Test circuit for measuring OFF-state current



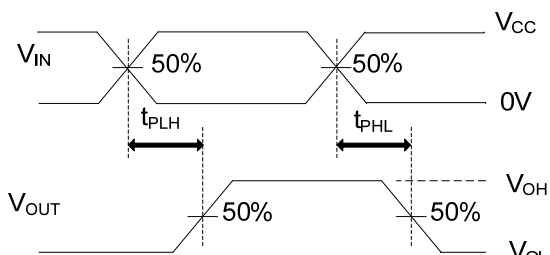
Test circuit for measuring ON-state current



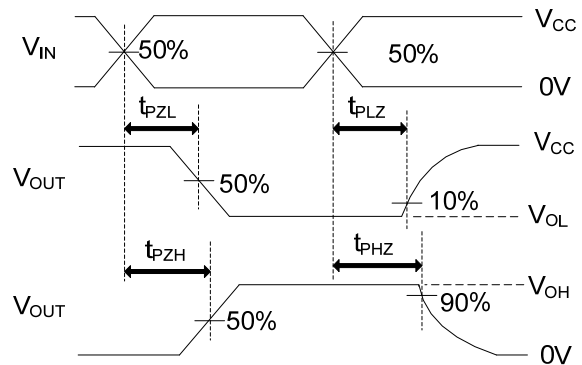
■ TEST CIRCUIT AND WAVEFORMS(Cont.)



	S	V _{IN}
t _{PLH} /t _{PHL}	OPEN	V _{CC}
t _{PHZ} /t _{PZH}	GND	V _{CC}
t _{PLZ} /t _{PZL}	V _{CC}	GND



PROPAGATION DELAY TIMES



ENABLE AND DISABLE TIMES

Note: 1. C_L includes probe and jig capacitance.
 Note: 2. PRR ≤ 1MHz, Z_o = 50Ω, t_r ≤ 6ns, t_f ≤ 6ns.

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